

# SILICON TRANSISTOR 2SD2230

## NPN SILICON EPITAXIAL TRANSISTOR FOR LOW-FREQUENCY POWER AMPLIFIERS

The 2SD2230 is an element realizing ultra low  $V_{\text{CE(sat)}}$ . This transistor is ideal for muting such as stereo recorders, VCRs, and TVs.

#### **FEATURES**

• Low VcE(sat):

 $V_{CE(sat)1} = 33 \text{ mV TYP}. \ @ Ic = 100 \text{ mA}, \ I_B = 10 \text{ mA}$  $V_{CE(sat)2} = 150 \text{ mV TYP}. \ @ Ic = 500 \text{ mA}, \ I_B = 20 \text{ mA}$ 

· High hee and high current

#### **QUALITY GRADES**

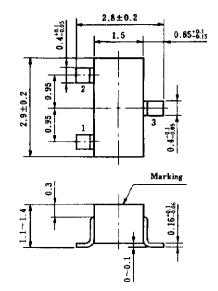
Standard

Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

#### ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vcво	16	V
Collector to emitter voltage	VCEO	16	V
Emitter to base voltage	VEBO	5	V
Collector current (DC)	I <sub>D(DC)</sub>	500	mA
Total power dissipation	Рт	200	mW
Junction temperature	Tj	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

#### PACKAGE DRAWING (UNIT: mm)



Electrode connection

- 1. Emitter (E)
- 2. Base (B)
- 3. Collector (C)

Marking: D46

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.



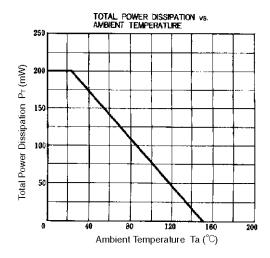
### **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

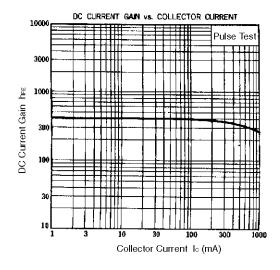
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	VcB = 16 V, IE = 0			100	nA
Emitter cutoff current	ІЕВО	V <sub>EB</sub> = 6.0 V, I <sub>C</sub> = 0			100	nA
DC current gain	h <sub>FE1</sub> *	VcE = 1.0 V, Ic = 100 mA	200			-
DC current gain	h <sub>FE2</sub> *	VcE = 1.0 V, Ic = 500 mA	200			-
DC base voltage	V <sub>BE</sub> *	VcE = 1.0 V, Ic = 10 mA	550		700	mV
Collector saturation voltage	V <sub>CE(sat)1</sub>	Ic = 100 mA, I <sub>B</sub> = 10 mA		33	50	mV
Collector saturation voltage	VCE(sat)2	Ic = 500 mA, I <sub>B</sub> = 20 mA		150	200	mV
Output capacitance	Cob	VcB = 10 V, IE = 0, f = 1.0 MHz			15	pF
Gain bandwidth product	f⊤	VcE = 1.0 V, IE = -100 mA	50			MHz

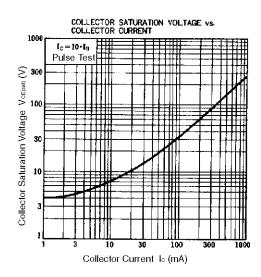
<sup>\*</sup> Pulse test PW  $\leq$  350  $\mu$ s, duty cycle  $\leq$  2%

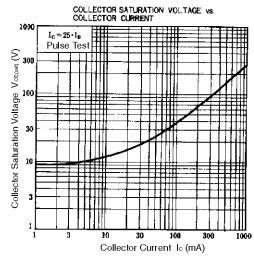


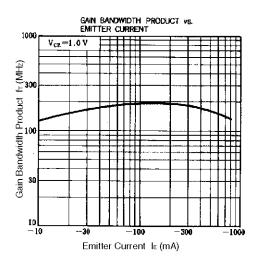
#### TYPICAL CHARACTERISTICS (Ta = 25°C)

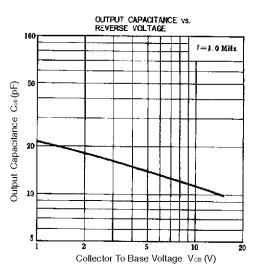












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#### RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, contact an NEC sales representative.

#### **Surface Mounting Type**

For details of the recommended soldering conditions, refer to the document **Semiconductor Device Mounting Technology Manual** (C10535E).

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Package peak temperature: 230°C, Time: 30 sec. max. (at 210°C or higher), Count: Once, Exposure limit: None*	IR30-00
VPS	Package peak temperature: 215°C, Time: 40 sec. max. (at 200°C or higher), Count: Once, Exposure limit: None*	VP15-00
Partial heating	Pin temperature: 300°C max., Time: 10 sec. max. Exposure limit: None*	0

<sup>\*</sup> After opening the dry pack, store it at 25°C or less and 65% RH or less for the allowable storage period.

Caution Do not use different soldering methods together (except for partial heating).

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[MEMO]

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